# **BC816** series

# 80 V, 500 mA NPN general-purpose transistors

Rev. 2 — 5 November 2019

**Product data sheet** 

## 1. General description

NPN general-purpose transistors in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

**Table 1. Product overview** 

Type number	Package		PNP complement:
	Nexperia	JEDEC	
BC816-16	SOT23	TO-236AB	BC806-16
BC816-25	SOT23	TO-236AB	BC806-25

### 2. Features and benefits

- High current
- High voltage
- · Two current gain selections
- AEC-Q101 qualified

## 3. Applications

- General-purpose switching and amplification
- · 48 V automotive board net

### 4. Quick reference data

### Table 2. Quick reference data

 $T_{amb}$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base		-	-	80	V
I <sub>C</sub>	collector current			-	-	500	mA
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-	1	А
h <sub>FE</sub>	DC current gain						
	BC816-16	V <sub>CE</sub> = 1 V; I <sub>C</sub> = 100 mA	[1]	100	-	250	
	BC816-25		[1]	160	-	400	

[1] pulsed;  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ 



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# 5. Pinning information

#### **Table 3. Pinning**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	]3	С
2	Е	emitter		
3	С	collector		B — [
				E sym123
			TO-236AB (SOT23)	Symr25

# 6. Ordering information

#### **Table 4. Ordering information**

Type number	Package	ackage						
	Name	Description	Version					
BC816-16	TO-236AB	plastic surface-mounted package; 3 leads	SOT23					
BC816-25								

## 7. Marking

#### Table 5. Marking

- abio of marking	
Type number	Marking code [1]
BC816-16	%GT
BC816-25	%GU

[1] % = placeholder for manufacturing site code

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# 8. Limiting values

#### **Table 6. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

 $T_{amb}$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter	open emitter		80	V
V <sub>CEO</sub>	collector-emitter voltage	open base	open base		80	V
V <sub>EBO</sub>	emitter-base voltage	open collector	open collector -		7	V
I <sub>C</sub>	collector current			-	500	mA
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	1	Α
I <sub>BM</sub>	peak base current	single pulse; t <sub>p</sub> ≤ 1 ms	single pulse; t <sub>p</sub> ≤ 1 ms		200	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	250	mW
			[2]	-	345	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

- [1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 1 cm<sup>2</sup>.

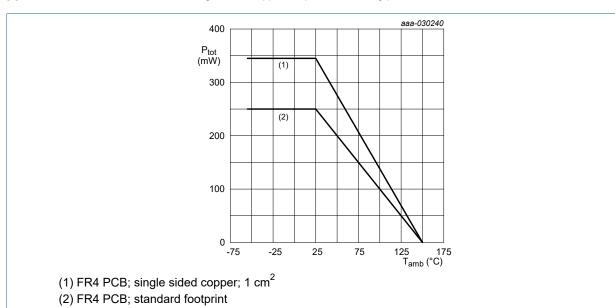


Fig. 1. Power derating curves

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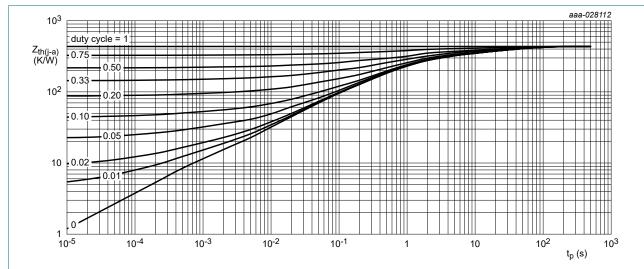
### 9. Thermal characteristics

#### **Table 7. Thermal characteristics**

 $T_{amb}$  = 25 °C unless otherwise specified.

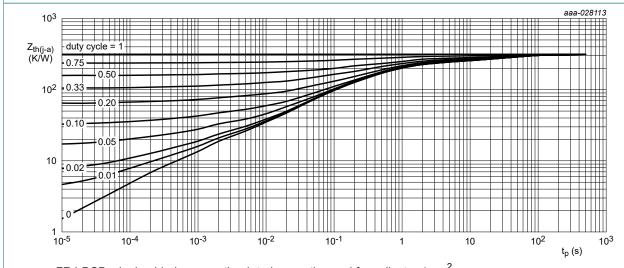
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	500	K/W
			[2]	-	-	363	K/W

- 1] Device mounted on an FR4 PCB; single-sided copper; tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 1 cm<sup>2</sup>.



FR4 PCB; single-sided copper; tin-plated and standard footprint

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 1 cm<sup>2</sup>

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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## 10. Characteristics

#### **Table 8. Characteristics**

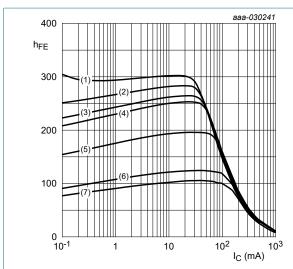
 $T_{amb}$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>(BR)CBO</sub>	collector-base breakdown voltage	I <sub>C</sub> = 100 μA; I <sub>E</sub> = 0 A		80	-		V
V <sub>(BR)CEO</sub>	collector-emitter breakdown voltage	I <sub>C</sub> = 2 mA; I <sub>E</sub> = 0 A		80	-		V
$V_{(BR)EBO}$	emitter-base breakdown voltage	I <sub>E</sub> = 100 μA; I <sub>C</sub> = 0 A		7	-		V
I <sub>CBO</sub>	collector-base	V <sub>CB</sub> = 64 V; I <sub>E</sub> = 0 A		-	-	100	nA
	cut-off current	V <sub>CB</sub> = 64 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C		-	-	5	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = 5.6 V; I <sub>C</sub> = 0 A		-	-	100	nA
h <sub>FE</sub>	DC current gain						
	BC816-16	V <sub>CE</sub> = 1 V; I <sub>C</sub> = 100 mA	[1]	100	-	250	
	BC816-25	V <sub>CE</sub> = 1 V; I <sub>C</sub> = 100 mA	[1]	160	-	400	
		V <sub>CE</sub> = 2 V; I <sub>C</sub> = 500 mA	[1]	30	-	-	
V <sub>CEsat</sub>	collector-emitter	I <sub>C</sub> = 100 mA; I <sub>B</sub> = 10 mA	[1]	-	-	-150	mV
	saturation voltage	I <sub>C</sub> = 500 mA; I <sub>B</sub> = 50 mA	[1]	-	-	400	mV
V <sub>BE</sub>	base-emitter voltage	V <sub>CE</sub> = 1 V; I <sub>C</sub> = 500 mA	[1]	-	-	1.2	V
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 50 mA; f = 100 MHz		100	-	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = I_e = 0 \text{ A}; f = 1 \text{ MHz}$		-	2	-	рF

<sup>[1]</sup> pulsed;  $t_p \le 300 \ \mu s; \ \delta \le 0.02$ 

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 $V_{CE} = 1 V$ 

(1)  $T_{amb} = 150 \, ^{\circ}C$ 

(2)  $T_{amb} = 125 \, ^{\circ}C$ 

(3)  $T_{amb}$  = 100 °C

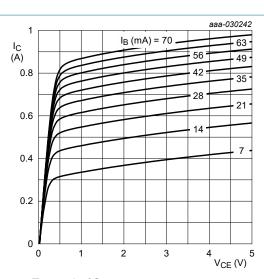
(4) T<sub>amb</sub> = 85 °C

(5)  $T_{amb} = 25 \, ^{\circ}C$ 

(6)  $T_{amb} = -40 \, ^{\circ}C$ 

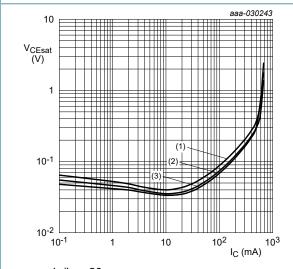
 $(7) T_{amb} = -55 °C$ 

Fig. 4. BC816-16: DC current gain as a function of collector current; typical values



 $T_{amb} = 25 \, ^{\circ}C$ 

Fig. 5. BC816-16: Collector current as a function of collector-emitter voltage; typical values



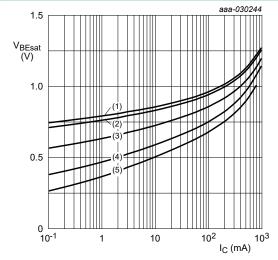
 $I_{\rm C}/I_{\rm B}=20$ 

(1)  $T_{amb} = 100 \, ^{\circ}C$ 

(2)  $T_{amb} = 25 \, ^{\circ}C$ 

(3)  $T_{amb} = -40 \, ^{\circ}C$ 

Fig. 6. BC816-16: Collector-emitter saturation voltage as a function of collector current; typical values



 $I_{\rm C}/I_{\rm B} = 10$ 

(1)  $T_{amb} = -55 \, ^{\circ}C$ 

(2)  $T_{amb} = -40 \, ^{\circ}C$ 

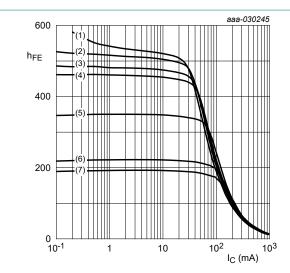
(3)  $T_{amb} = 25 \, ^{\circ}C$ 

(4)  $T_{amb}$  = 100 °C

(5) T<sub>amb</sub> = 150 °C

Fig. 7. BC816-16: Base-emitter saturation voltage as a function of collector current; typical values

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 $V_{CE} = 1 V$ 

(1)  $T_{amb} = 150 \, ^{\circ}C$ 

(2)  $T_{amb} = 125 \, ^{\circ}C$ 

(3)  $T_{amb}$  = 100 °C

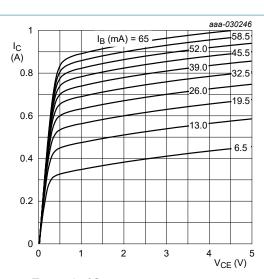
(4) T<sub>amb</sub> = 85 °C

(5)  $T_{amb} = 25 \, ^{\circ}C$ 

(6)  $T_{amb} = -40 \, ^{\circ}C$ 

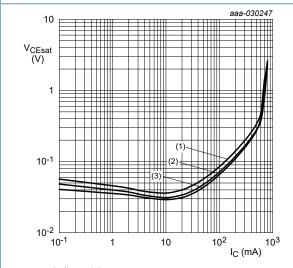
 $(7) T_{amb} = -55 °C$ 

Fig. 8. BC816-25: DC current gain as a function of collector current; typical values



 $T_{amb} = 25 \, ^{\circ}C$ 

Fig. 9. BC816-25: Collector current as a function of collector-emitter voltage; typical values



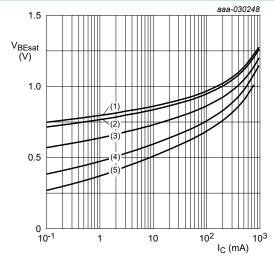
 $I_{\rm C}/I_{\rm B}=20$ 

(1)  $T_{amb} = 100 \, ^{\circ}C$ 

(2)  $T_{amb} = 25 \, ^{\circ}C$ 

(3)  $T_{amb} = -40 \, ^{\circ}C$ 

Fig. 10. BC816-25: Collector-emitter saturation voltage as a function of collector current; typical values



 $I_{\rm C}/I_{\rm B} = 10$ 

(1)  $T_{amb} = -55$  °C

(2)  $T_{amb} = -40 \, ^{\circ}C$ 

(3)  $T_{amb} = 25 \, ^{\circ}C$ 

(4)  $T_{amb}$  = 100 °C

 $(5) T_{amb} = 150 °C$ 

Fig. 11. BC816-25: Base-emitter saturation voltage as a function of collector current; typical values

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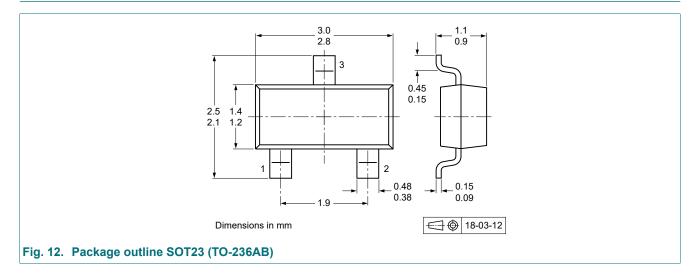
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## 11. Test information

## 11.1. Quality information

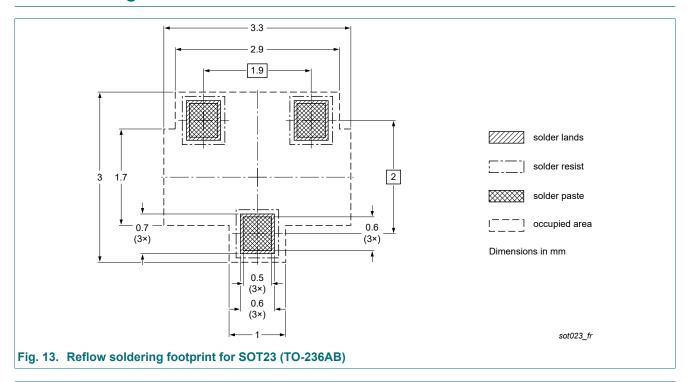
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

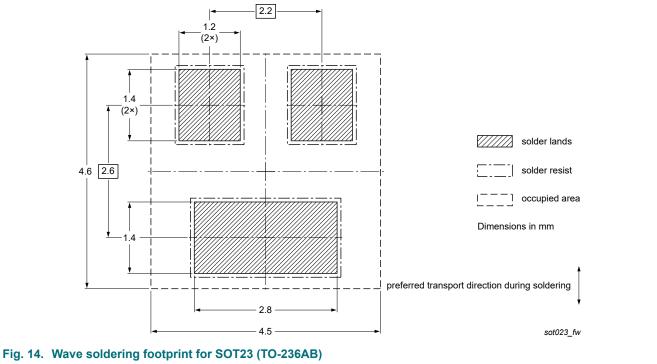
## 12. Package outline



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## 13. Soldering





**Product data sheet** 

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# 14. Revision history

#### Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
BC816_SER v.2	20191105	Product data sheet	-	BC816_SER v.1			
Modifications:	Product status change	Product status changed					
BC816_SER v.1	20190904	Preliminary data sheet	-	-			

**Product data sheet** 

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### 15. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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